

## 1-Line Ultra Low Capacitance Bi-directional TVS Diode

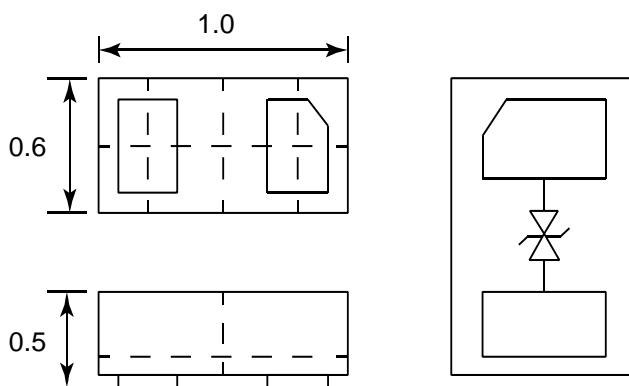
### Description

The PESDR1261P1 is a bi-directional TVS diode, to provide fast response time and low ESD clamping voltage, making this device an ideal solution for protecting voltage sensitive high-speed data lines. The PESDR1261P1 has an ultra-low capacitance with a typical value at 0.6pF, and complies with the IEC 61000-4-2 (ESD) with  $\pm 15\text{kV}$  air and  $\pm 10\text{kV}$  contact discharge. It is assembled into an ultra-small 1.0x0.6x0.5mm lead-free DFN package. The small size, ultra-low capacitance and high ESD surge protection make PESDR1261P1 an ideal choice to protect cell phone, digital visual interfaces and other high speed ports.

### Features

- Ultra small package: 1.0x0.6x0.5mm
- Ultra low capacitance: 0.6pF typical
- Ultra low leakage: nA level
- Operating voltage: 12V
- Low clamping voltage
- 2-pin leadless package
- Complies with following standards:
  - IEC 61000-4-2 (ESD) immunity test
    - Air discharge:  $\pm 15\text{kV}$
    - Contact discharge:  $\pm 10\text{kV}$
  - IEC 61000-4-5 (Lightning) 4A (8/20 $\mu\text{s}$ )
- RoHS Compliant

### Dimensions and Pin Configuration



Package Dimensions

Circuit and Pin Schematic

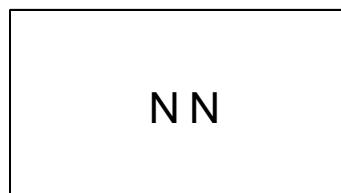
### Mechanical Characteristics

- Package: DFN1006-2 (1.0x0.6x0.5mm)
- Case Material: "Green" Molding Compound.
- Moisture Sensitivity: Level 3 per J-STD-020
- Marking Information: See Below

### Applications

- Cellular Handsets & Accessories
- Personal Digital Assistants (PDAs)
- Notebooks & Handhelds
- Portable Instrumentation
- Digital Cameras
- MP3 Players

### Marking Information



NN = Device Marking Code

### Ordering Information

Part Number	Shipping	Reel Size
PESDR1261P1	10000/Tape & Reel	7 inch

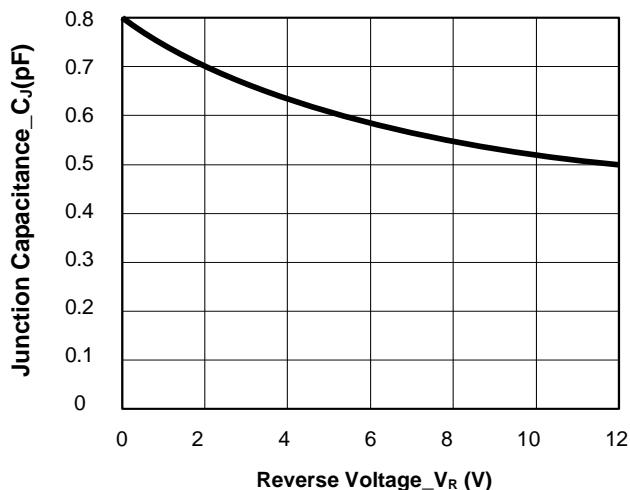
**Absolute Maximum Ratings ( $T_A=25^\circ\text{C}$  unless otherwise specified)**

Parameter	Symbol	Value	Unit
Peak Pulse Power (8/20μs)	$P_{PK}$	140	W
Peak Pulse Current (8/20μs)	$I_{PP}$	4	A
ESD per IEC 61000-4-2 (Air) ESD per IEC 61000-4-2 (Contact)	$V_{ESD}$	±15 ±10	kV
Operating Temperature Range	$T_{OP}$	-55 to +125	°C
Storage Temperature Range	$T_{STG}$	-55 to +150	°C

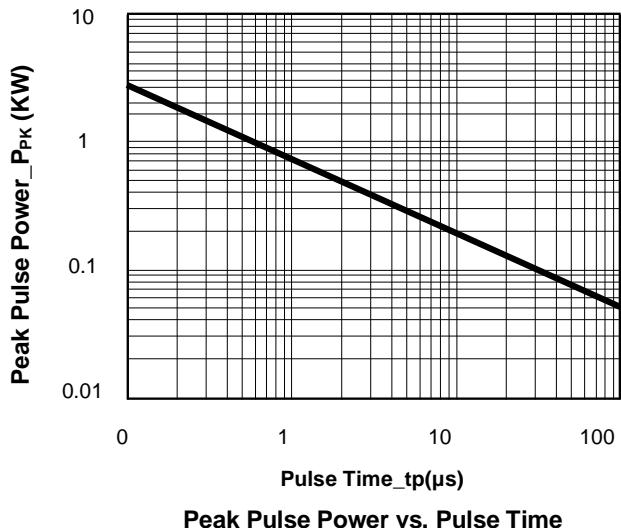
**Electrical Characteristics ( $T_A=25^\circ\text{C}$  unless otherwise specified)**

Parameter	Symbol	Min	Typ	Max	Unit	Test Condition
Reverse Working Voltage	$V_{RWM}$			12	V	
Breakdown Voltage	$V_{BR}$	13.3			V	$I_T = 1\text{mA}$
Reverse Leakage Current	$I_R$			200	nA	$V_{RWM} = 12\text{V}$
Clamping Voltage	$V_C$		22	25	V	$I_{PP} = 1\text{A}$ (8/20μs pulse)
Clamping Voltage	$V_C$		32	35	V	$I_{PP} = 4\text{A}$ (8/20μs pulse)
Junction Capacitance	$C_J$		0.6	0.8	pF	$V_R = 0\text{V}$ , $f = 1\text{MHz}$

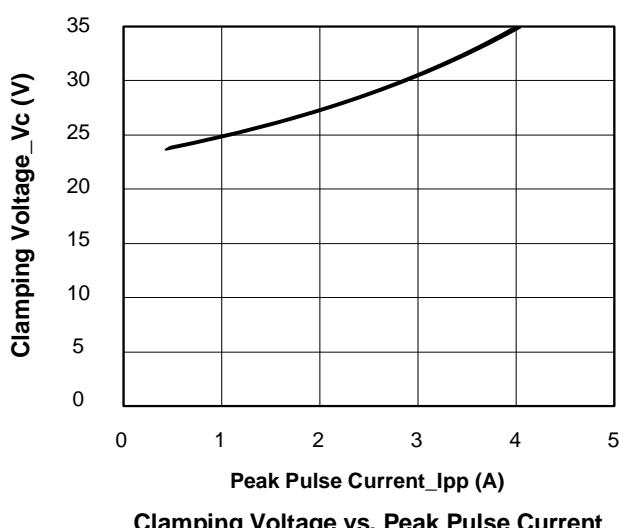
**Typical Performance Characteristics ( $T_A=25^\circ\text{C}$  unless otherwise Specified)**



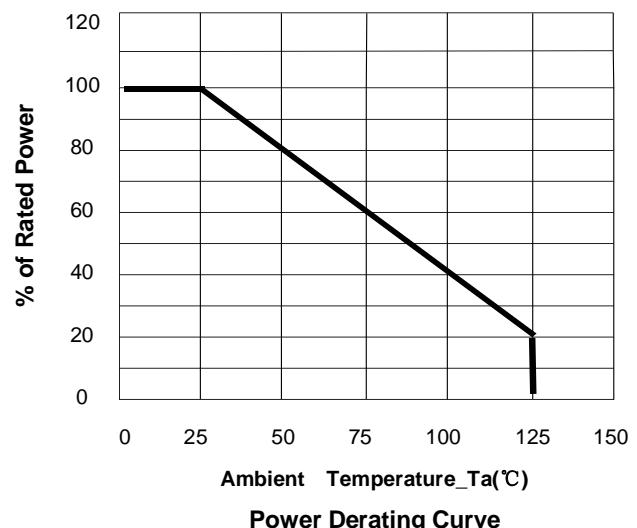
**Junction Capacitance vs. Reverse Voltage**



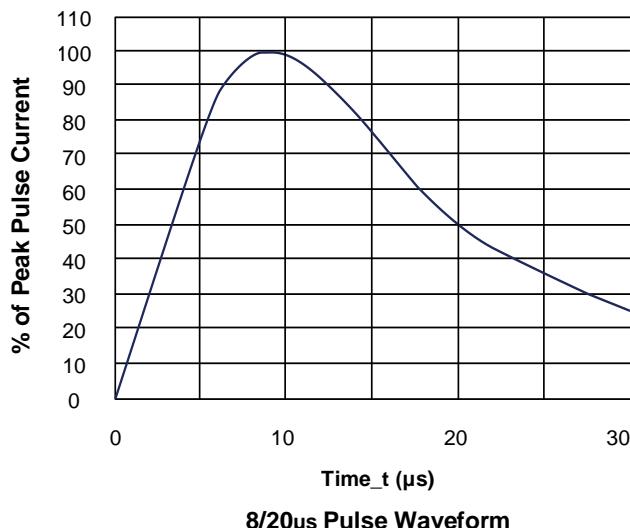
**Peak Pulse Power vs. Pulse Time**



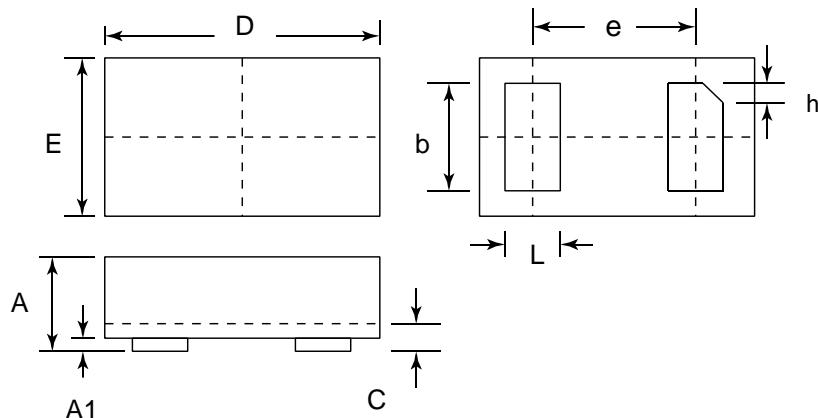
**Clamping Voltage vs. Peak Pulse Current**



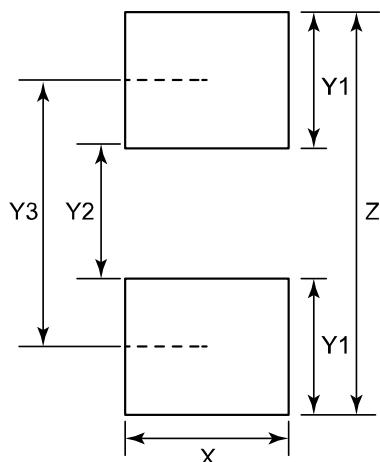
**Power Derating Curve**



**8/20 $\mu\text{s}$  Pulse Waveform**

DFN1006-2 Package Outline Drawing

SYM	DIMENSIONS					
	MILLIMETERS			INCHES		
	MIN	NOM	MAX	MIN	NOM	MAX
A	0.45	0.50	0.55	0.018	0.020	0.022
A1	0.00	0.02	0.05	0.000	0.001	0.002
b	0.45	0.50	0.55	0.018	0.020	0.022
c	0.12	0.15	0.18	0.005	0.006	0.007
D	0.95	1.00	1.05	0.037	0.039	0.041
e	0.65 BSC			0.026 BSC		
E	0.55	0.60	0.65	0.022	0.024	0.026
L	0.20	0.25	0.30	0.008	0.010	0.012
h	0.07	0.12	0.17	0.003	0.005	0.007

Suggested Land Pattern

SYM	DIMENSIONS	
	MILLIMETERS	INCHES
X	0.60	0.024
Y1	0.50	0.020
Y2	0.30	0.012
Y3	0.80	0.032
Z	1.30	0.052